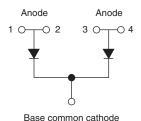


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# Not Insulated SOT-227 Power Module Ultrafast Rectifier, 310 A





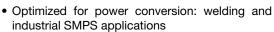
PRODUCT SUMMARY						
$V_{R}$	400 V					
I <sub>F(AV)</sub> at T <sub>C</sub> = 119 °C per module <sup>(1)</sup>	310 A					
t <sub>rr</sub>	39 ns					
at T <sub>C</sub>	135 °C					
Туре	Modules - Diode, FRED Pt®					

#### Note

(1) All 4 anode terminals connected

#### **FEATURES**

- · Not insulated package
- · Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape



- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- · Direct mounting to heatsink
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

The VS-UFB310CB40 not insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	$V_R$		400	V	
Continuous forward current per diode	I <sub>F</sub> <sup>(1)</sup>	T <sub>C</sub> = 135 °C	155	Α	
Single pulse forward current per diode	I <sub>FSM</sub> <sup>(2)</sup>	T <sub>C</sub> = 25 °C	1300	A	
Maximum power dissipation per module	$P_{D}$	T <sub>C</sub> = 135 °C	421	W	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	

#### Notes

Maximum I<sub>RMS</sub> current per leg 200 A to do not exceed the maximum temperature of terminals

<sup>(1)</sup> Both anode terminals connected;

<sup>(2) 10</sup> ms sine or 6 ms rectangular pulse



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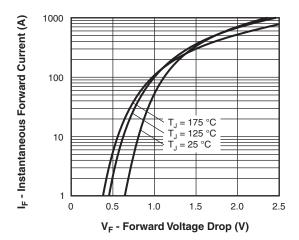
<b>ELECTRICAL SPECIFICATIONS PER DIODE</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	$V_{BR}$	I <sub>R</sub> = 100 μA	400	-	-	
		I <sub>F</sub> = 100 A	-	1.11	1.34	
	V <sub>FM</sub>	I <sub>F</sub> = 100 A, T <sub>J</sub> = 125 °C	-	0.99	1.1	V
Forward voltage, per leg		I <sub>F</sub> = 100 A, T <sub>J</sub> = 175 °C	-	0.97	-	
		I <sub>F</sub> = 200 A	-	1.3	1.6	
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 125 °C	-	1.22	1.4	
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 175 °C	-	1.25	-	
		$V_R = V_R$ rated	-	1.3	50	
Reverse leakage current, per leg	I <sub>RM</sub>	V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 125 °C	-	100	-	μA
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 175 °C	-	1	4	mA
Junction capacitance, per leg	C <sub>T</sub>	V <sub>R</sub> = 400 V	-	100	-	pF

<b>DYNAMIC RECOVERY CHARACTERISTICS PER DIODE</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 400 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	39	-	
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	89	-	ns
		T <sub>J</sub> = 125 °C	$I_F = 50 \text{ A}$	-	184	-	
Deel, were sure as week and a sure as	1	T <sub>J</sub> = 25 °C		-	9	-	Α
Peak recovery current, per leg I <sub>RRM</sub>		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	20	-	A
Davis and a second of the seco	0	T <sub>J</sub> = 25 °C		-	400	=	nC
Reverse recovery charge, per leg Q <sub>rr</sub>		T <sub>J</sub> = 125 °C		-	1840	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55	-	175	°C
Junction to case, single leg conducting	В		-	-	0.19	
Junction to case, both leg conducting	R <sub>thJC</sub>		-	-	0.095	°C/W
Case to heatsink	R <sub>thCS</sub>	Flat, greased surface	-	0.07	-	
Weight			-	30	-	g
Mounting torque			-	-	1.3	Nm
Case style			SOT-227			

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10 000 1000 I<sub>R</sub> - Reverse Current (µA) 100 = 125 °C 10  $T_{.1} = 25 \, ^{\circ}\text{C}$ 0.1 0.01 150 200 250 300 350 400 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Leg

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

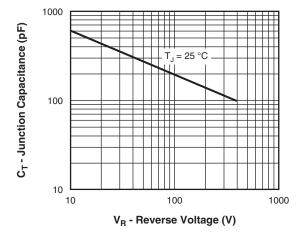


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

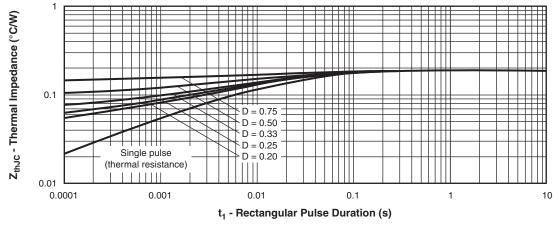


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics, Per Leg



Allowable Case Temperature (°C)

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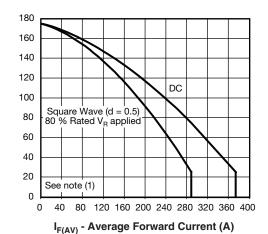


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

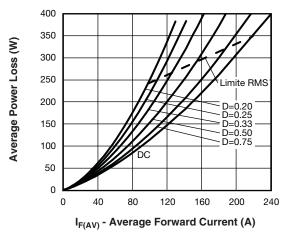


Fig. 6 - Forward Power Loss Characteristics, Per Leg

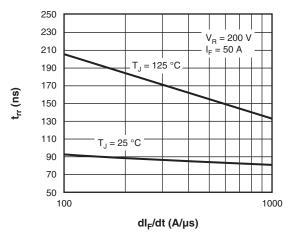


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt, Per Leg

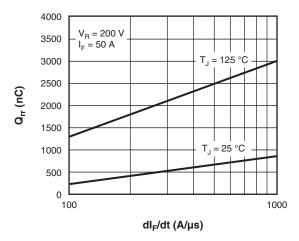


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt, Per Leq

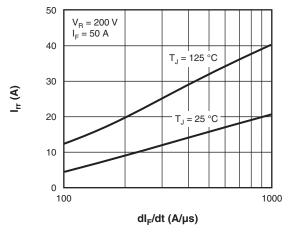


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt, Per Leg

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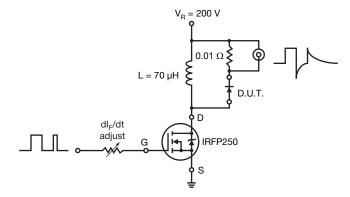
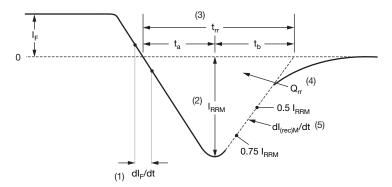


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm l_F$  to point where a line passing through 0.75  $\rm l_{RRM}$  and 0.50  $\rm l_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

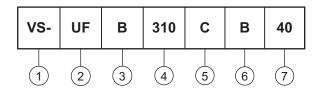
Fig. 11 - Reverse Recovery Waveform and Definitions



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### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Ultrafast rectifier
- Ultrafast Pt diffused
- 4 Current rating (310 = 310 A)
- 5 Circuit configuration (2 common cathode diodes)
  - Package indicator (SOT-227 standard not insulated)
- 7 Voltage rating (40 = 400 V)

Quantity per tube is 10 pcs, M4 screw and washer included

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Common cathodes diodes, not in insulated base	С	Lead Assignment  40  Base  10  2				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95423			
Packaging Information	www.vishay.com/doc?95425			



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Revision: 02-Oct-12 Document Number: 91000



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